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FSUSB104 — Low-Power, Two-Port, Hi-Speed, USB2.0 (480 Mbps) Switch



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Features

- Low On Capacitance: 3.7 pF Typical
- Low On Resistance: 3.9 Ω Typical
- Low Power Consumption: 1 µA Maximum
 - 15 μA Maximum I_{CCT} over an Expanded Voltage Range (V_{IN}=1.8 V, V_{CC}=4.3 V)
- Wide -3 db Bandwidth: > 720 MHz
- Packaged in Pb-free 10-Lead UMLP (1.4 x 1.8 mm)
- 8 kV ESD Rating, >16 kV Power/GND ESD Rating
- Power-Off Protection on All Ports When V_{CC}=0 V
 D+/D- Pins Tolerate up to 5.25 V

Applications

- Cell phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-Top Box

Description

The FSUSB104 is a bi-directional, low-power, two-port, Hi-Speed, USB2.0 switch. Configured as a double-pole, double-throw switch (DPDT) switch, it is optimized for switching between two Hi-Speed (480 Mbps) sources or a Hi-Speed and Full-Speed (12 Mbps) source.

The FSUSB104 is compatible with the requirements of USB2.0 and features an extremely low on capacitance (C_{ON}) of 3.7 pF. The wide bandwidth of this device (720 MHz) exceeds the bandwidth needed to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk also minimizes interference.

The FSUSB104 contains special circuitry on the switch I/O pins for applications where the V_{CC} supply is powered-off (V_{CC} =0), which allows the device to withstand an over-voltage condition. This device is designed to minimize current consumption even when the control voltage applied to the SEL pin is lower than the supply voltage (V_{CC}). This feature is especially valuable to ultra-portable applications, such as cell phones, allowing for direct interface with the general-purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSUSB104UMX	JF	-40 to +85°C	10-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 1.4 x 1.8 mm
		HSD1+	
		HSD2+	→ D+
		HSD1- HSD2-	• D-
		Sel - Contro	ol /OE
		Figure 1. Analog	g Symbol

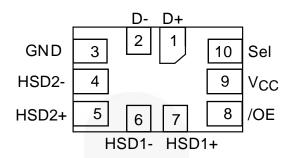


Figure 2. Pin Assignment (Top Through View)

Pin Definitions

Pin #	Name	Description
1	D+	USB Data Bus
2	D-	USB Data Bus
3	GND	Ground
4	HSD2-	Multiplexed Source Inputs
5	HSD2+	Multiplexed Source Inputs
6	HSD1-	Multiplexed Source Inputs
7	HSD1+	Multiplexed Source Inputs
8	/OE	Switch Enable
9	Vcc	Supply Voltage
10	Sel	Switch Select

Truth Table

Sel	/OE	Function
Х	HIGH	Disconnect
LOW	LOW	D+, D-=HSD1+, HSD1-
HIGH	LOW	D+, D-=HSD2+, HSD2-

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Parameter			
Vcc	Supply Voltage	-0.5	5.6	V	
V _{CNTRL}	DC Input Voltage (S, /OE) ⁽¹⁾	-0.5	V _{CC}	V	
Vsw	DC Switch I/O Voltage ⁽¹⁾	-0.5	5.25	V	
I _{IK}	DC Input Diode Current	-50		mA	
lout	DC Output Current		50	mA	
T _{STG}	Storage Temperature	-65	+150	°C	
		All Pins		7	
FOD	Human Body Model, JEDEC: JESD22-A114	I/O to GND		8	1.27
ESD		Power to GND		16	kV
	Charged Device Model, JEDEC: JESD22-C10		2		

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	3.0	4.4	V
V _{CNTRL}	Control Input Voltage (S, /OE) ⁽²⁾	0	V _{cc}	V
Vsw	Switch I/O Voltage	-0.5	4.5	V
TA	Operating Temperature	-40	+85	°C

Note:

2. The control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Devementer	Conditions	V _{cc} (V)	T _A =- 40°C to +85°C			Unite
Symbol	Parameter	Conditions		Min.	Тур.	Max.	Units
V _{IK}	Clamp Diode Voltage	I _{IN} =-18 mA	3.0			-1.2	V
N/	lanut Voltono Llink		3.0 to 3.6	1.3			V
Vih	Input Voltage High		4.3	1.7			V
V	Innut Voltage Low		3.0 to 3.6			0.5	V
V _{IL}	Input Voltage Low		4.3			0.7	V
l _{in}	Control Input Leakage	V _{SW} =0 to V _{CC}	4.3	-1		1	μA
I _{OZ}	Off State Leakage	$0 \le Dn$, HSD1n, HSD2n $\le 3.6V$	4.3	-2		2	μA
IOFF	Power-Off Leakage Current (All I/O Ports)	V_{SW} =0 V to 4.3 V, V_{CC}=0 V Figure 4	0	-2		2	μA
R _{on}	HS Switch On Resistance ⁽³⁾	V_{SW} =0.4 V, I _{ON} =-8 mA Figure 3,	3.0		3.9	6.5	Ω
ΔR_{ON}	HS Delta Ron ⁽⁴⁾	V _{SW} =0.4 V, I _{ON} =-8 mA	3.0		0.65		Ω
Icc	Quiescent Supply Current	V _{CNTRL} =0 or V _{CC} , I _{OUT} =0	4.3			1.0	μA
	Increase in I _{cc} Current per	V _{CNTRL} =2.6 V, V _{CC} =4.3 V	4.3			10.0	μA
I _{CCT}	Control Voltage and V_{CC}	V _{CNTRL} =1.8 V, V _{CC} =4.3 V	4.3			15.0	μA

Notes:

3. Measured by the voltage drop between HSDn and Dn pins at the indicated current through the switch.

On resistance is determined by the lower of the voltage on the two (HSDn or Dn ports).

4. Guaranteed by characterization. Not tested in production.

AC Electrical Characteristics

All typical value are for V_{CC} =3.3 V at 25°C unless otherwise specified.

Symbol	Parameter	Conditions		T _A =- 40°C to +85°C			Units
Symbol			V _{cc} (V)	Min.	Тур.	Max.	Units
t _{ON}	Turn-On Time S, /OE to Output	R_L =50 Ω , C_L =5 pF V _{SW} =0.8 V Figure 5, Figure 6	3.0 to 3.6		13	30	ns
toff	Turn-Off Time S, /OE to Output	R_L =50 Ω , C_L =5 pF V _{SW} =0.8 V Figure 5, Figure 6	3.0 to 3.6		12	25	ns
t _{PD}	Propagation Delay ⁽⁵⁾	$C_{L}=5 \text{ pF}, R_{L}=50 \Omega$ Figure 5, Figure 7	3.3		0.25		ns
t _{ввм}	Break-Before-Make	$\begin{array}{l} R_{L} = \! 50 \; \Omega, \; C_{L} \! = \! 5 \; pF \\ V_{SW1} \! = \! V_{SW2} \! = \! 0.8 \; V \\ Figure 9 \end{array}$	3.0 to 3.6	2.0		6.5	ns
O _{IRR}	Off Isolation	R∟=50 Ω, f=240 MHz Figure 11	3.0 to 3.6		-30		dB
Xtalk	Non-Adjacent Channel Crosstalk	R∟=50 Ω, f=240 MHz Figure 12	3.0 to 3.6		-45		dB
BW	2db Dondwidth	$R_{L}=50 \Omega, C_{L}=0 pF$ Figure 10	- 3.0 to 3.6		720		MHz
DVV	-3db Bandwidth	$R_L=50 \Omega$, $C_L=5 pF$ Figure 10	3.0 10 3.6		550		MHz

Note:

5. Guaranteed by characterization. Not tested in production.

USB Hi-Speed-Related AC Electrical Characteristics

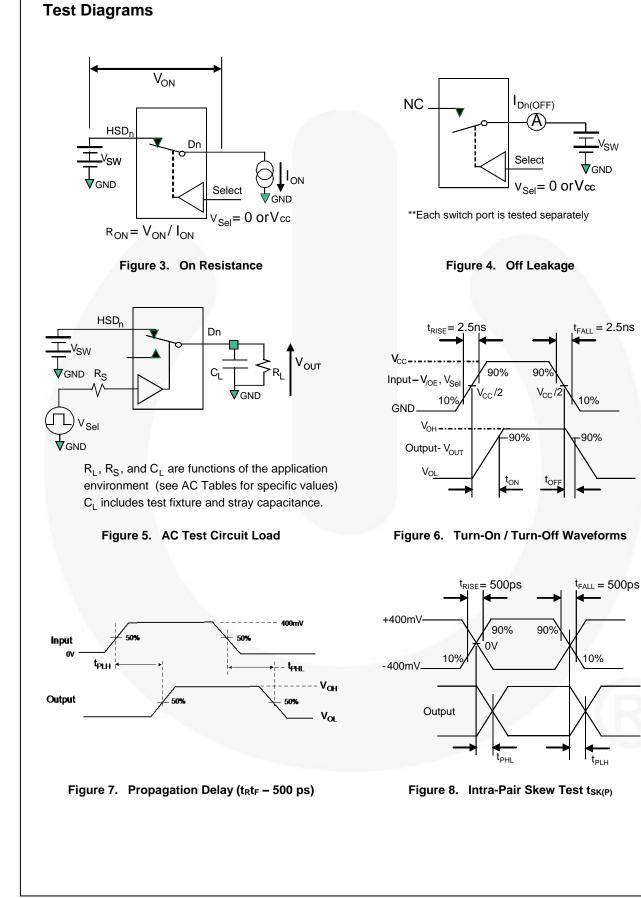
Symbol	Deremeter	Conditions	Vcc (V)	T _A =- 40°C to +85°C			Unito
	Parameter			Min.	Тур.	Max.	Units
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽⁶⁾	$C_L=5 \text{ pF}, R_L=50 \Omega$ Figure 8	3.0 to 3.6		20		ps
tj	Total Jitter ⁽⁶⁾	$R_L=50 \Omega$, $C_L=5 pf$, $t_R=t_F=500ps$ (10-90%) at 480 Mbps (PRBS=2 ¹⁵ – 1)	3.0 to 3.6		200		ps

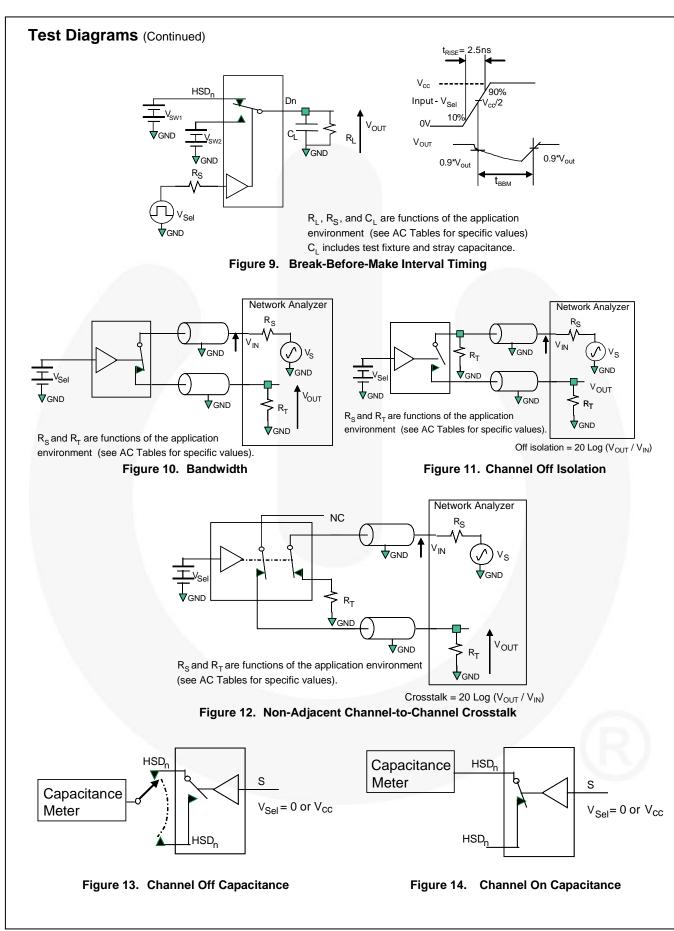
Note:

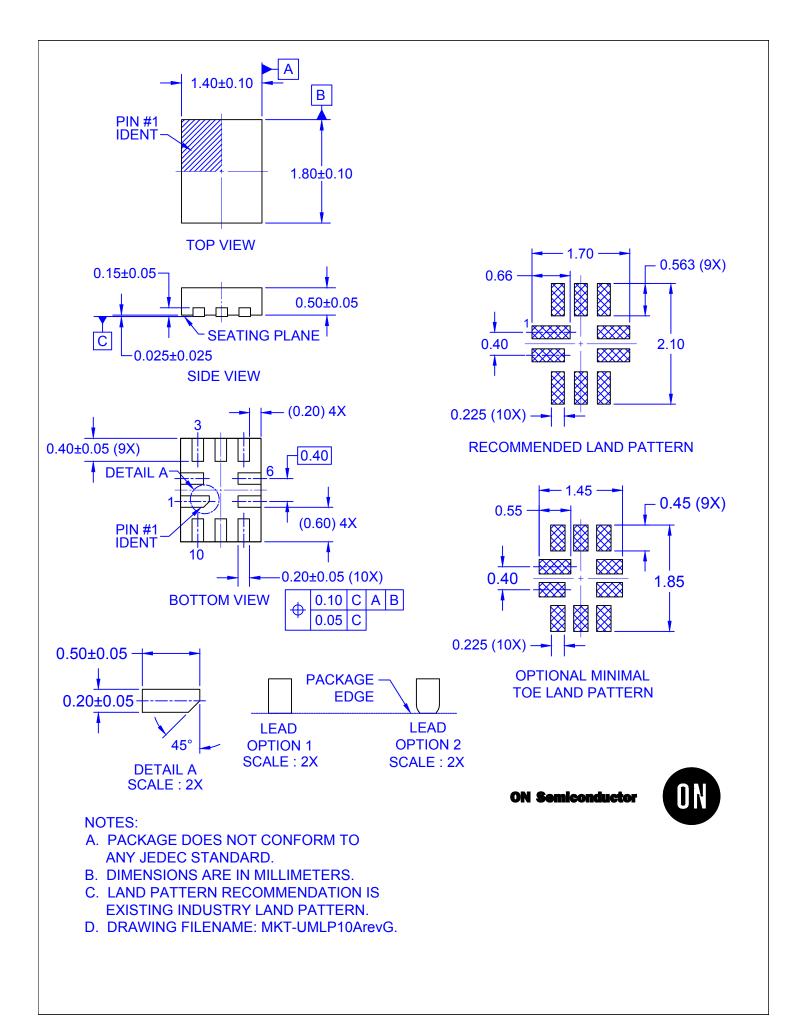
6. Guaranteed by characterization. Not tested in production.

Capacitance

Symbol	Deveneter	Conditions	T _A =- 40°C to +85°C			Unite
	Parameter	Conditions	Min.	Тур.	Max.	Units
C _{IN}	Control Pin Input Capacitance	V _{cc} =0 V		1.5		
Con	D+/D- On Capacitance	V _{CC} =3.3 V, /OE=0 V, f=240 MHz Figure 14		3.7		pF
C _{OFF}	D1n, D2n Off Capacitance	V _{CC} and /OE=3.3 V See Figure 13		2.0		







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